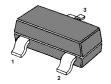
# Silicon Epitaxial Planar Switching Diode

#### **Feature**

- · Low leakage switching double diode
- Very low leakage current
- Medium speed switching times
- Series pair configuration





1. Anode 2. Andoe 3. Cathode SOT-23 Plastic Package

### **Applications**

· Low leakage current applications

# Absolute Maximum Ratings ( $T_a = 25$ °C)

Parameter	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage		$V_{RRM}$	85	V
Continuous Reverse Voltage		$V_R$	85	V
Continuous Forward Current	Single Diode Double Diode	I <sub>F(AV)</sub>	215 125	mA
Repetitive Peak Forward Current		I <sub>FRM</sub>	500	mA
Non-Repetitive Peak Forward Surge Current	at t = 1 µs at t = 1 ms at t = 1 s	I <sub>FSM</sub>	4 1 0.5	А
Power Dissipation		$P_{D}$	250	mW
Operating Junction and Storage Temperature	$T_{j},T_{stg}$	- 65 to + 150	°C	

#### **Thermal Characteristics**

Parameter	Symbol	Max.	Unit	
Thermal Resistance, Junction to Ambient 1)	$R_{ hetaJA}$	500	°C/W	

<sup>&</sup>lt;sup>1)</sup>Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



# **BAV170**

## Characteristics at $T_a = 25$ °C

Parameter	Symbol	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage at I <sub>R</sub> = 100 μA	V <sub>(BR)R</sub>	85	-	-	V
Forward Voltage at $I_F = 1$ mA at $I_F = 10$ mA at $I_F = 50$ mA at $I_F = 150$ mA	V <sub>F</sub>			0.9 1 1.1 1.25	V
Reverse Current at $V_R = 75 \text{ V}$ at $V_R = 75 \text{ V}$ , $T_j = 150 \text{ °C}$	I <sub>R</sub>	-	-	5 80	nA
Total Capacitance at $V_R = 0 \text{ V}$ , $f = 1 \text{ MHz}$	C <sub>tot</sub>	-	2	-	pF
Reverse Recovery Time at $I_F = I_R = 10$ mA, $I_{rr} = 0.1$ X $I_R$ , $R_L = 100$ $\Omega$	t <sub>rr</sub>	1	ı	3	μs



#### **Electrical Characteristic Curve**

Fig 1. Power Derating Curve

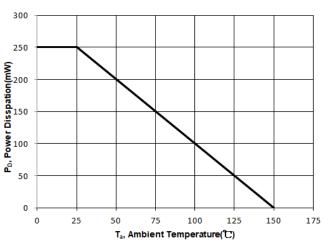


Fig 2. Capacitance Characteristics Curve

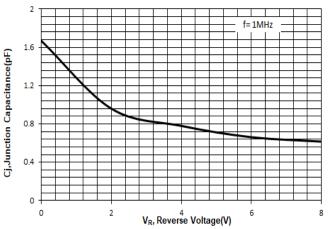


Fig 3. Reverse Characteristics Curve

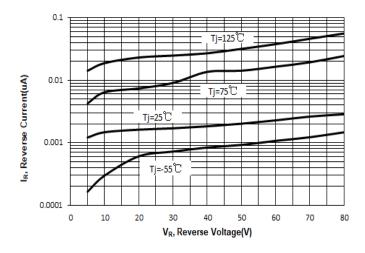
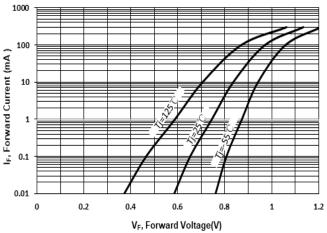
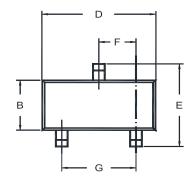


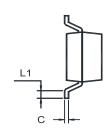
Fig 4. Forward Characteristics Curve



### Package Outline (Dimensions in mm)

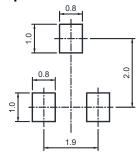
**SOT-23** 





\ <del></del>										
Unit	Α	A1	∟ BJ F	C	$q_A^lp$	Е	F	G	L	L1
mm	1.20	0.100	1.40	0.19	3.04	2.6	1.02	2.04	0.51	0.2
mm	0.89	0.013	1.20	0.08	2.80	2.2	0.89	1.78	0.37	MIN

### **Recommended Soldering Footprint**



**Packing information** 

Facking information									
	Package	Tape Width	Pitch		Reel Size		D D 10 11 0 11		
		(mm)	mm	inch	mm	inch	Per Reel Packing Quantity		
	SOT-23	8	4 ± 0.1	0.157 ± 0.004	178	7	3,000		

## **Marking information**

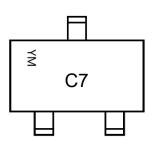
" C7 " = Part No.

"YM" = Date Code Marking

"Y" = Year

"M" = Month

Font type: Arial



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